# NSN 5961-01-024-4458

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.252 inches

# **Overall Height:**

Between 0.250 inches and 0.340 inches

#### **Overall Width:**

0.700 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

#### Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 50.0 emitter to base voltage,

static, collector open

# **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 1.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

82577-928776 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

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